Supporting Information:

Functionalized Carbon Nanotube Adsorption Interfaces for Electron Transfer Studies of Galactose Oxidase

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Figure SI-1. Electrochemical techniques to confirm modification of the gold electrode including **(A)** capacitance measurements of as received gold (black trace), clean bare gold (blue trace), and TA-SAM modified gold (red trace); **(B)** cyclic volammetry and **(C)** differential pulse voltammetry of 5 mM Fe(CN)₆^{3-/4-} (0.5 M KCl) redox probe at clean bare (blue trace) and TA-SAM modified gold (red trace). Note: scan rate is 0.020 V/sec.



Figure SI-2. Typical cyclic voltammetry of GaOx adsorbed at a 4-mercaptoaniline (4-aminothiophenol, 4-ATP) modified electrode in 20 mM MES buffer (pH 7.5) at a scan rate of 0.020 V/sec..

			Est. ET							
Platform	Adsorption	#	Distance ^a	E _{p,c}	E _{p,a}	Ë,	ΔE_p	L ^c ^b	ker ^{0 c}	FWHM ^d
	Interface	Film	(min-max)	S	S	3	S	(pmol/cm ²)	(s ⁻¹)	S
		S	(mm)							
Au	Au	9	~0.8-9	0.125	0.274	0.199	0.149	30.9	1.2	0.170
				(0.01)	(0.02)	(0.01)	(0.03)	(8.3)	(0.08)	(0.030)
4-ATPh SAM		3	~1.3-9.5	0.108	0.253	0.149	0.208	2.8	0.66	0.059
				(0.02)	(0.01)	(0.02)	(0.06)	(0.52)	(0.12)	(0.009)
CYST-SAM		3	~1.1-9.3	0.105	0.278	0.192	0.173	43.7	0.82	0.162
				(0.02)	(00.0)	(0.01)	(0.02)	(9.4)	(0.03)	(0.003)
TA-SAM	COOH	2	0.78-9.7	0.086	0.232	0.159	0.146	64.8	0.42	0.139
				(0.001)	(0.00_3)	(0.001)	(0.003)	(8.4)	(0.04)	(0.007)
+ MAS-AM +	2HN	2	~150-250	0.061	0.288	0.175	0.227	35.5	0.676	0.160
NH2 MWCNT				(0.00_1)	(0.04)	(0.02)	(0.04)	(6.5)	(0.10)	(0.010)
TA-SAM +		4	~20-30	0.073	0.277	0.162	0.231	40.2	0.55	0.123
NH2-SWCNT				(0.01)	(0.03)	(0.01)	(0.05)	(6.7)	(0.05)	(0.007)
CYST-SAM +	COOH	4	~150-250	0.131	0.257	0.194	0.126	27.9	0.34	0.163
COOH-MWCNT				(0.01)	(0.01)	(E00.0)	(0.01)	(7.3)	(0.04)	(0.008)
CYST-SAM +	COOH	5	~20-30	0.107	0.260	0.183	0.153	68.1	0.74	0.174
COOH-SWCNT				(0.01)	(0.01)	(0.01)	(0.01)	(9.4)	(0.09)	(0.010)
Notes: Uncertainty () re	presents standard en	ror. "Min	mum and maxim	um ET dista	nce estimate	ed from mo	deling, prior	studies of protei	m adsorption t	to SAMs [24], the
GaOx structure (globula	r metalloprotem with	dimensio	or of 9.8 x 8.9 x 8	S.7 nm and th	he copper n	edox center	0.8 nm from	a surface represent	nting minimu	n ET distance

Platforms	
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within enzyme)[4], and analysis of the cross-sectional TEM of the CNT films (Figure 5) and Supporting Information; ^b Apparent surface coverage (T_c) is calculated from charge passed during cathodic cyclic voltammetry peak without de-convolution of two separate electron transfers (n=2) demonstrated in prior work and likely resulting in the observed elevated values [4]; ^e Calculated using Laviron's Theorem for diffusionless (adsorbed) electrochemical systems [41] assuming a charge transfer coefficient of 0.5; ^d As estimation calculated from convoluted peak and should not be interpreted as a single ET where ideal adsorbed, reversible behavior would result in a FWHM of .091 V.

	4.1		T	T	T ⁰ ,	1.5	T	1 0
	Adsorption		Łp,c	Ł _{p,a}	E	ΔE_p	I c	KET ^o
Platform	Interface	n	(V)	(V)	(V)	(V)	(pmol/cm ²)	(s ⁻¹)
TA-SAM	COOH	2	0.086	0.232	0.159	0.146	64.8	0.42
			(0.001)	(0.003)	(0.001)	(0.003)	(8.4)	(0.04)
TA Exchanged	COOH/OH	1	0.009	NP	N/A	N/A	47.38	(N/A)
With MUD								
TA Exchanged	COOH/CH ₃	1	NP	NP	N/A	N/A	(N/P)	(N/A)
With C8								
TA Exchanged	COOH/OH	1	0.039	0.282	0.160	0.243	14.97	(N/A)
With MHOL								
TA Exchanged	COOH	1	0.009	0.255	0.132	0.246	223.2	(N/A)
With MUA								
MHA SAM	COOH	5	0.064	0.248	0.156	0 184	169	0.082
		-	(0.01)	(0.01)	(0.01)	(0.007)	(28.0)	(0.01)
MHA/MUA	COOH	5	0.005	0.246	0.126	0.242	137	0.033
SAM			(0.01)	(0.01)	(0.01)	(0.008)	(19.2)	(0.006)
MHA/MUD	COOH/OH	2	0.021	0.251	0.136	0.230	126	0.034
SAM			(0.009)	(0.02)	(0.02)	(0.01)	(9.3)	(0.009)
MHA/MHOL	COOH/OH	2	0.038	0.268	0.153	0.230	50.2	0.031
SAM								(0.006)

Table SI-1. Electrochemical Parameters for GaOx Adsorbed at Various Modified Electrode Platforms

Notes: TA = thioctic acid; MUD = 11-mercaptoundecanol; C8 = octane thiol; MHOL = mercaptohexanol; MUA = 11-mercaptoundecanoic acid; MHA = mercaptohexanoic acid; COOH = carboxylic acid functionality; OH = hydroxyl group functionality; CH₃ = methyl group functionality. All parameters measured at 20 mV/sec except k_{err}° (Laviron's Theorem); Uncertainty represents standard error.

Platform	Adsorption Interface	n	E _{p,c} (V)	E _{p,a} (V)	E°. (V)	Δ Ε _P (V)	Γ_c (pmol/cm ²)	ket ⁰ (s ⁻¹)
MUA/ CSNPs	COOH	3	0.107 (0.00 ₈)	0.243 (0.00 ₆)	0.175 (0.00 ₆)	0.136 (0.00 ₈)	265.9 (71.8)	0.150 (0.03)
MHA/CSNPs	COOH	3	0.077 (0.01)	0.263 (0.01)	0.170 (0.003)	0.186 (0.02)	557.3 (43.5)	0.137 (0.07)
BPDT SAM/PLL /TASNP	COOH	3	0.023 (0.04)	0.295 (0.02)	0.114 (0.008)	0.363 (0.03)	9.137 (3.0)	0.483 (0.11)
C6-BPDT SAM/ TASNP	COOH	3	-0.058 (0.00 ₆)	0.135 (0.005)	0.039 (0.005)	0.192 (0.00 ₂)	2.606 (0.56)	0.122 (0.00)
C6-NDT SAM/ TASNP	COOH	3	-0.072 (0.00 ₈)	0.153 (0.00)	0.041 (0.003)	0.225 (0.00 ₈)	1.730 (0.19)	0.051 (0.005)

Table SI-2. Electrochemical Parameters for GaOx Adsorbed at Various Modified Electrode Platforms

Notes: MUA = 11-mercaptoundecanoic acid; PLL = poly-L-lysine, cationic linker; CS-NP = citrate-stabilized gold nanoparticles; MHA = mercaptohexanoic acid; BPDT = biphenyldithiol; TAS-NPs = thioctic acid stabilized gold nanoparticles; C6 = hexanethiol; NDT = nonanedithiol. All parameters measured at 20 mV/sec except k_{eff}° (Laviron's Theorem); Uncertainty represents standard error.



Figure SI-3. Typical differential pulse voltammetry (DPV) of 5 mM $Fe(CN)_6^{3-/4-}$ (0.5 M KCl) at the same interfaces described in (A) Figure 2 and (B) Figure 3 of the paper, respectively. Specific interfaces include (top, A) (a) CYST-SAM modified gold, (b) CYST-SAM with amide-coupled COOH-SWCNT, and (c) CYST-SAM with amide-coupled COOH-SWCNTs in 8 mM KPB (pH 10) and; (bottom, B) (a) TA-SAM modified gold, (b) TA-SAM with amide-coupled NH₂-SWCNTs.





Figure SI-4. Cross-sectional TEM imaging of the COOH-SWCNT films that comprise the GaOx adsorption interface. Notes: small black circles are believed to be CNT overlap sites whereas the large white structure is believed to be a bubble in the epoxy resin used to lift the film (see Experimental Details).



Figure SI-5. Cyclic voltammetry of GaOx adsorbed at TA-SAM modified electrodes amidecoupled with NH_2 -**MW**CNTs at increasing scan rates (v) with linear plot (**below**) of log peak current ($I_{p,c}$) versus log of scan rate v, linear for non-diffusional (adsorbed) behavior.



Figure SI-6. Cyclic voltammetry of GaOx adsorbed at TA-SAM modified electrodes amidecoupled with NH_2 -SWCNTs at increasing scan rates (v) with linear plots (below) of log peak current ($I_{p,c}$) versus log of scan rate v, linear for non-diffusional (adsorbed) behavior.



Figure SI-7. Cyclic voltammetry of GaOx adsorbed at CYST-SAM modified electrodes amidecoupled with COOH-**MW**CNTs at increasing scan rates (υ) with linear plots (**below**) of log peak current ($I_{p,c}$) versus log of scan rate υ , linear for non-diffusional (adsorbed) behavior.



Figure SI-8. Comparison of representative cyclic voltammetry of GaOx adsorbed at day 0 (*solid, blue trace*) and day 8 (*red, dashed traces*) for GaOx adsorbed to bare gold. Notes: Scan rate is 0.020 V/sec;



Figure SI-9. Tracking of apparent ET rate constant (k_{ET}^{o}) over time for GaOx at bare gold, CYST-SAM and CYST-SAM/COOH-SWCNT platforms.



Figure SI-10. H_2O_2 fluorescence assay results showing relative fluorescence intensity representing GaOx activity (H_2O_2 production) in the presence of galactose substrate from aliquots sampled from electrochemical cells with Au/CYST-SAM/COOH-SWCNT/GaOx films on Day 1 (Cells 1-4) and Day 6 (Cell 5), the latter including measurements of the soaking buffer (L) and new buffer after 5 minutes of exposure to 50 µL of 10 mM galactose.





Figure SI-11. HRP-coupled fluorescence kinetic assay for hydrogen peroxide production experiment including (A) example set-up using whole films of Au/CYST-SAM/COOH-SWCNT/GaOx constructed within the electrochemical cell (film area ~ 0.32 cm²) submerged in a 6-well plate and exposed to 10 mM galactose; (B) fluorescence generation ($\lambda_{ex} = 540$ nm, $\lambda_{em} = 590$ nm) over time comparing films with native GaOx, GaOx denatured using heat, urea, and glycine, and without GaOx (control). Initial rates were determined from linear fit of the first 180 seconds of data.

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Figure SI-12. Representative amperometric I-t curve (A) and corresponding calibration curve (B) during injection of galactose (Gal) with 1 mM increases every 100s, **black arrows**) into a stirred buffer solution at a gold electrode (+0.65V) modified with CYST-SAM/COOH-SWCNT/GaOx (\leq monolayer) and capped with polyurethane help retain H₂O₂ that is generated by the enzymatic reaction. **Inset:** The same experiment without enzyme (control).



Figure SI-13. Representative amperometric I-t curve (A) and corresponding calibration curve (B) where GaOx was used in a traditional 1st generation biosensing scheme involving the complete encapsulation of GaOx **multi-layer** within a isobutyltrimethoxysilane (IBTMS) sol-gel layer at a platinum electrode (+0.65V), capped with another IBTMS layer and a polyurethane layer to help retain H_2O_2 generated by the enzymatic reaction produced with successive injections of galactose (1 mM every 100s, **black arrows**). Note that as more enzyme is immobilized on the surface (multi-layer vs. monolayer), the signal is increased by an order of magnitude as expected from more active enzyme being available.



Figure SI-14. Representative examples of cyclic voltammetry of (A) GaOx adsorbed to a COOH-SWCNT/CYST SAM/Au platform and corresponding background (no GaOx) in the presence of oxygen and; (B) the same platforms in the presence and absence of oxygen. Notes: Solution is 20 mM MES buffer (pH 7.5) at a scan rate of 0.020 V/sec.); solutions were scrubbed with catalase agarose beads prior to conducting the experiments.



Figure SI-15. Representative examples of cyclic voltammetry of (A) GaOx adsorbed to a COOH-SWCNT/CYST SAM/Au platform and corresponding background (no enzyme) in the presence/absence of oxygen with galactose (10 mM) and; (B) the same platforms in the presence/absence of oxygen with galactose (10 mM) and catalase enzyme (CAT, 10 μ M). Notes: Solution is 20 mM MES buffer (pH 7.5) at a scan rate of 0.020 V/sec; solutions were scrubbed with catalase agarose beads prior to conducting the experiments.



Figure SI-16. Representative examples of cyclic voltammetry of GaOx adsorbed to a COOH-SWCNT/CYST SAM/Au platform (A) in the presence and (B) absence of oxygen before (a) and after (b) exposure to galactose (10 mM). Notes: Solution is 20 mM MES buffer (pH 7.5) at a scan rate of 0.020 V/sec; solutions were scrubbed with catalase agarose beads prior to conducting the experiments.



Figure SI-17. Representative amperometric I-t curves during injection of galactose (Gal) substrate injections (1 mM increases every 100s, **black arrows**) into a stirred PB solution that has been purged of O_2 at a gold electrode (+0.65V) with GaOx (*top three traces, blue*) and without GaOx (*bottom trace, no enzyme control*) adsorbed to a COOH-SWCNT/CYST-SAM modified gold electrode - each capped with polyurethane. Notes: Solutions were scrubbed with catalase agarose beads prior to conducting the experiments.